

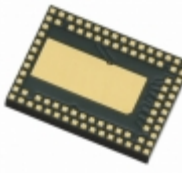


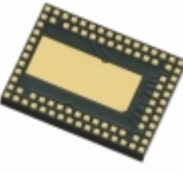



	<p>SI1032R-T1-E3</p>
	<p>Hersteller-Teilenummer: SI1032R-T1-E3</p> <p>Hersteller / Marke: Vishay / Siliconix</p> <p>Teil der Beschreibung: MOSFET N-CH 20V 140MA SC-75A</p> <p>Datenblätter:  SI1032R-T1-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 104017 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p>
<p>Image may be representation. See specs for product details.</p>	

Spezifikationen

Teilenummer	SI1032R-T1-E3
Hersteller	Vishay / Siliconix
Beschreibung	MOSFET N-CH 20V 140MA SC-75A
Kategorie	Diskrete Halbleiterprodukte > Transistoren-FETs,
Teilstatus	104017 pcs Stock
Serie	TrenchFET®
Technologie	MOSFET (Metal Oxide)
Betriebstemperatur	-55°C ~ 150°C (TJ)
Befestigungsart	Surface Mount
Verpackung / Gehäuse	SC-75A
Supplier Device-Gehäuse	SC-75A
Verlustleistung (max)	250mW (Ta)
Typ FET	N-Channel
FET-Merkmal	-
Drain-Source-Spannung (Vdss)	20V
Strom - Ununterbrochener Abfluss (Id) bei 25 ° C	140mA (Ta)
Rds On (Max) @ Id, Vgs	5 Ohm @ 200mA, 4.5V
VGS (th) (Max) @ Id	1.2V @ 250µA
Gate Charge (Qg) (Max) @ Vgs	0.75nC @ 4.5V
Eingabekapazität (Ciss) (Max) @ Vds	-
Verpackung	Tape & Reel (TR)



















































SI1032R-T1-E3 ist neu im Original, Suche SI1032R-T1-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SI1032R-T1-E3 Vishay / Siliconix mit Garantie und Vertrauen.
Anfrage SI1032R-T1-E3: Info@Y-IC.com

Sie können auch interessiert sein:

 <p>SI1032R-T1-GE3 Vishay / Siliconix MOSFET N-CH 20V 140MA SC-75A</p>	 <p>SI1032-B-GM3R Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1032R-T1-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 140MA SC-75A</p>	 <p>SI1032R-T1 VISHAY SI1032R-T1 VISHAY</p>
 <p>SI1032-B-GM3 Energy Micro (Silicon Labs) IC RF TXRX+MCU ISM<1GHZ 85-VFLGA</p>	 <p>SI1032X-T1 SILICON SI1032X-T1 SILICON</p>	 <p>SI1032X VISHAY SI1032X VISHAY</p>	 <p>SI1032R-T1-E3 Electro-Films (EFI) / Vishay MOSFET N-CH 20V 140MA SC-75A</p>

heiße Teile

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|---|---|--|---|--|
|  SI1024X-T1-GE3 |  SI1025X-T1 |  SI1025X-T1-E3 |  SI1025X-T1-E3 |  SI1026X-T1 |
|  SI1026X-T1-E3 |  SI1026X-T1-E3 |  SI1026X-T1-GE3 |  SI1026X-T1-GE3 |  SI1028X-T1-GE3 |
|  SI1028X-T1-GE3 |  SI1029X-T1-GE3 |  SI1029X-T1-GE3 |  SI1031R-T1 |  SI1031R-T1-E3 |
|  SI1031R-T1-E3 |  SI1031R-T1-GE3 |  SI1031R-T1-GE3 |  SI1031X-T1 |  SI1031X-T1-E3 |
|  SI1031X-T1-E3 |  SI1031X-T1-GE3 |  SI1031X-T1-GE3 |  SI1032R-T1 |  SI1032R-T1-E3 |
|  SI1032R-T1-GE3 |  SI1032R-T1-GE3 |  SI1032X-T1 |  SI1032X-T1-E3 |  SI1032X-T1-E3 |
|  SI1032X-T1-GE3 |  SI1032X-T1-GE3 |  SI1033X-T1 |  SI1033X-T1-E3 |  SI1033X-T1-E3 |
|  SI1034CX-T1-GE3 |  SI1034CX-T1-GE3 |  SI1034X-T1 |  SI1034X-T1-E3 |  SI1034X-T1-E3 |
|  SI1034X-T1-GE3 |  SI1034X-T1-GE3 |  SI1035X-T1 |  SI1035X-T1-E3 |  SI1035X-T1-E3 |
|  SI1035X-T1-GE3 |  SI1035X-T1-GE3 |  SI1039X-T1-E3 |  SI1039X-T1-E3 |  SI1040X-T1-E3 |

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